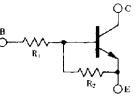


COMPOUND TRANSISTOR BA1L3M

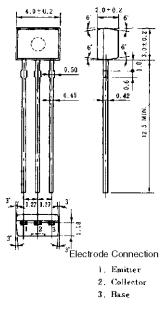
on-chip resistor NPN silicon epitaxial transistor For mid-speed switching

FEATURES

- · On-chip bias resistor $(R_1 = 4.7 \text{ k}\Omega, R_2 = 4.7 \text{ k}\Omega)$
- Complementary transistor with BN1L3M



PACKAGE DRAWING (UNIT: mm)



ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vсво	60	V
Collector to emitter voltage	VCEO	50	V
Emitter to base voltage	VEBO	10	V
Collector current (DC)	IC(DC)	100	mA
Collector current (Pulse)	IC(pulse) *	200	mA
Total power dissipation	Р⊤	250	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	–55 to +150	°C

* PW \leq 10 ms, duty cycle \leq 50 %

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	Vcb = 50 V, IE = 0			100	nA
DC current gain	hfe1 **	Vce = 5.0 V, Ic = 5.0 mA	20	40	80	-
DC current gain	hfe2 **	Vce = 5.0 V, Ic = 50 mA	70	140		-
Collector saturation voltage	V _{CE(sat)} **	Ic = 5.0 mA, Iв = 0.25 mA		0.08	0.3	V
Low level input voltage	VIL **	Vce = 5.0 V, Ic = 100 µA		1.1	0.2	V
High level input voltage	VIH **	Vce = 0.2 V, Ic = 5.0 mA	3.0	1.5		V
Input resistance	R1		3.29	4.7	6.11	kΩ
Resistance ratio	R1/R2		0.9	1.0	1.1	-
Turn-on time	ton	$V_{CC} = 5 V, R_L = 1 k\Omega$			0.5	μs
Storage time	tstg	$V_{I} = 5 V, PW = 2 \mu s$			3.0	μs
Turn-off time	t _{off}	duty cycle≤2 %			5.0	μs

** PW \leq 350 μ s, duty cycle \leq 2 %

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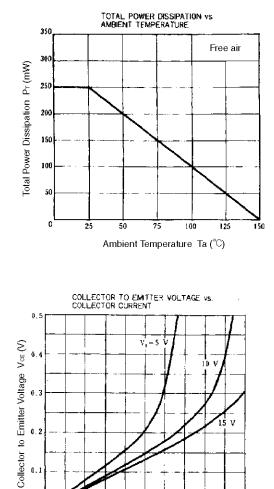
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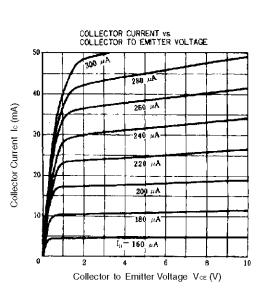
Collector Current Ic (mA)

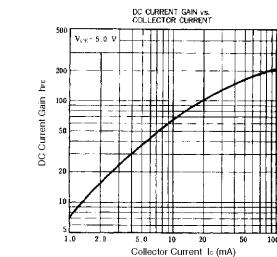
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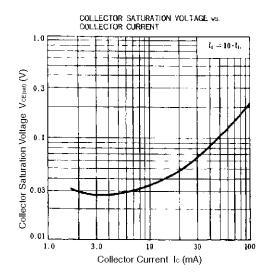
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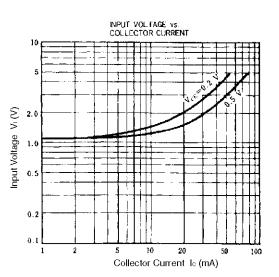
TYPICAL CHARACTERISTICS (Ta = 25°C)



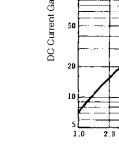


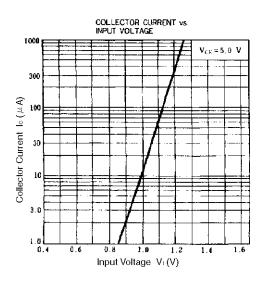


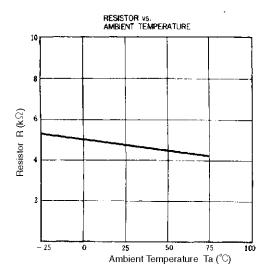




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